

NEW

Electron Detection Unit

H8770

PATENT PENDING

HAMAMATSU has introduced new Electron Detection Unit H8770, consist of newly developed extremely fast decay phosphor and high sensitivity compact PMT. Decay time of the phosphor is faster than 2.3 ns, and it can present high speed electron detection. Built-in PMT power supply, high speed amplifier and other circuitry provide its easy operation.

APPLICATIONS

- Semiconductor Inspection System
- Scanning Electron Microscope (SEM)
- Mass Spectrometer (MS)
- General Electron Detection

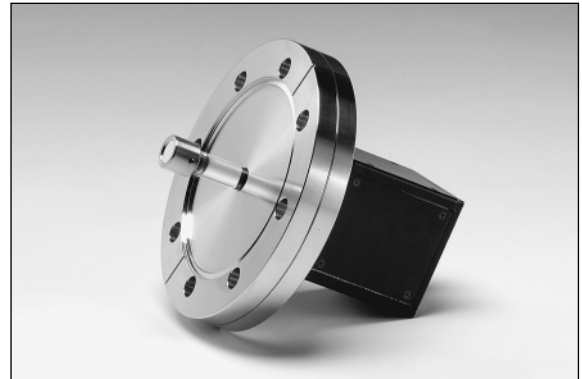
FEATURES

- Fast Decay Phosphor Decay Time: 2.3 ns Typ.
- Long Life Phosphor: Low Degradation Against Electron Irradiation
- High Sensitivity Compact PMT
- Built-in High Voltage Power Supply, Voltage Divider Circuit for PMT and High Speed Amplifier (upto 150 MHz)
- Vacuum Flange ICF114 is assembled (Custom assembly is available upon request)

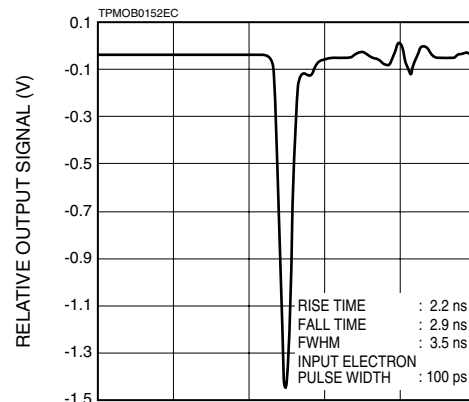
SPECIFICATIONS

Parameter	Description/Value
Phosphor Screen Effective Area ^①	φ9 mm
Type of Phosphor	Fast Decay Phosphor
Light Guide Material	Synthetic Silica ^②
Light Detector	Photomultiplier tube
Detectable Input Electron Energy Range	5 keV to 12 keV
Electron-to-Voltage Conversion	1.4 V/nA ^③
PMT Gain Range	1×10^2 to 1×10^6 ^④
Built-in Amplifier Frequency Bandwidth	DC to 150 MHz
Maximum Output Voltage	-1.4 V ^⑤
Offset Voltage	±10 mV Max.
Noise Level	20 mV (Typ.)
Input Voltage	±15 V ±1 V
Input Current	Approx. +130 mA/-40 mA
Type of Vacuum Flange	ICF114
Operating Temperature Range	+5 °C to +45 °C ^⑥
Weight	Approx. 1.5 kg

NOTE: ① Other dimension is available upon request.
② Plastic can be chosen. Custom design is also available.
③ At input electron energy : 6 keV, PMT gain: 1×10^4
④ Adjustable by controll voltage (+1 V to +4 V)
⑤ At 50 Ω load resistance
⑥ Without condensation

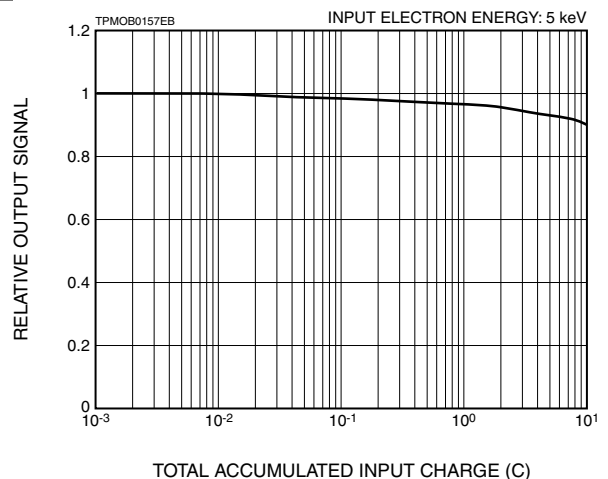


Time Response (Output Waveform)



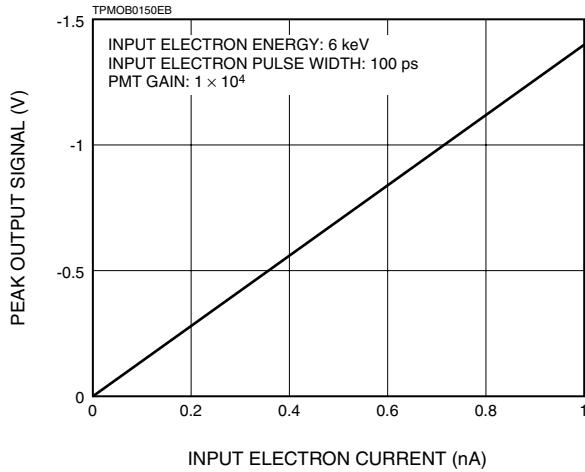
TIME (20 ns/div.)

Phosphor Life Characteristics

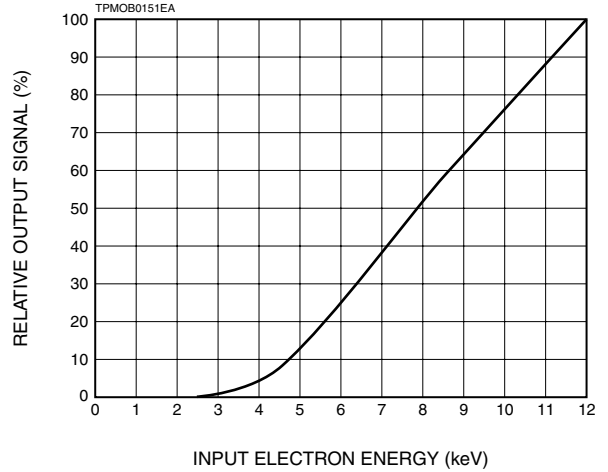


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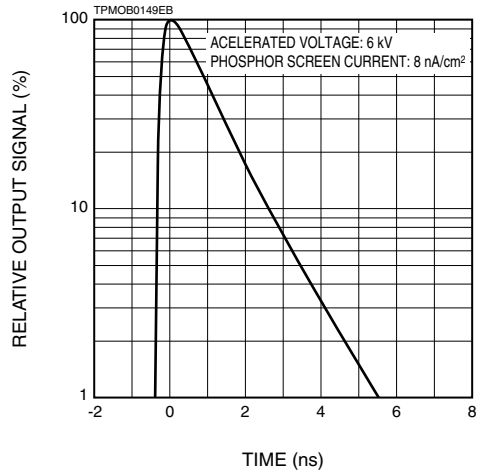
Output Signal as a function of input electron current



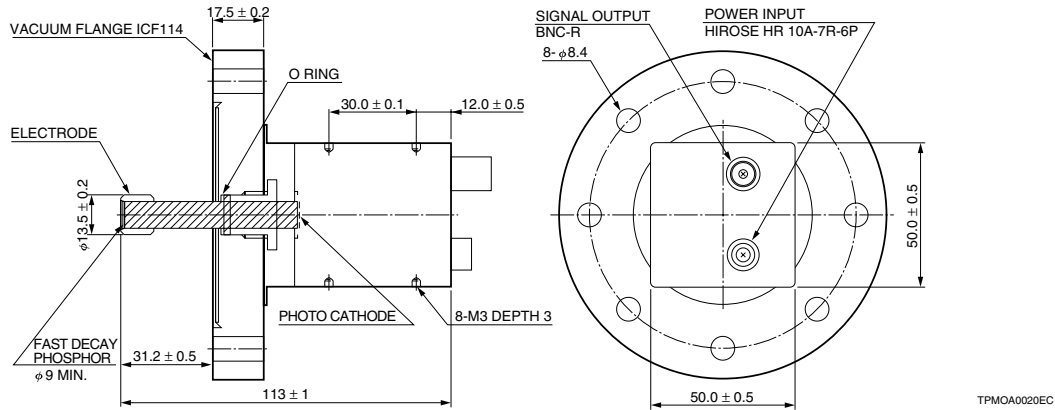
Output Signal as a function of Input Electron Energy



Phosphor Decay Characteristics



DIMENSIONAL OUTLINES (Unit: mm)



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PATENT PENDING : JAPAN 1, USA 1, EUROPE 1

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